

Notice of Allowability	Application No.	Applicant(s)	
	10/064,375	FIFIELD ET AL.	
	Examin r	Art Unit	
	Donghee Kang	2811	
		<u> </u>	
The MAILING DATE of this communication appears on the cover sheet with the correspondenc address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.			
1. This communication is responsive to <u>January 16, 2004</u> .			
2. The allowed claim(s) is/are <u>1-17</u> .			
3. The drawings filed on are accepted by the Examiner.			
 4. ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have been received. 			
2. Certified copies of the priority documents have been received in Application No			
3. Copies of the certified copies of the priority documents have been received in this national stage application from the			
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.			
5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.			
6. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.			
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached			
1) hereto or 2) to Paper No./Mail Date			
(b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date			
Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).			
7. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.			
Attachment(s)	E T Notice of Information	-44 Alinetian (DT)	O 152)
1. Notice of References Cited (PTO-892)	5. Notice of Informal P	* * * * * * * * * * * * * * * * * * * *	J-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary Paper No./Mail Dat 08), 7. ☑ Examiner's Amendo		
 Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 	·		
4. Examiner's Comment Regarding Requirement for Deposit	8. 🛛 Examiner's Stateme	ent of Reasons for Allo	owance
of Biological Material	9. Other		
		Donghee Kang Examiner Art Unit: 2811	

DETAILED ACTION

EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Mr. Robert A. Walsh on February 03, 2004.

The application has been amended as follows:

In claim 1, line 5, add "having an FET" after a second gain device.

Allowable Subject Matter

2. Claims 1-17 are allowed.

The following is a statement of reasons for the indication of allowable subject matter:

Chen et al. (US 5,656,534) appears to be the closest prior art reference. Chen et al. teaches a programmable element, comprising :

A first device on a substrate having a first electrode and a first insulator disposed between the substrate and said first electrode, said first insulator having a first value of a given parameter; a second device on a substrate having a second electrode and a second insulator disposed between the substrate and said second electrode, said second insulator having a second value of said given parameter that is different from

said first value; wherein said first and second electrodes of said first and second device are coupled to one another on a continuous layer.

However, this reference fails to teach that the second gain device comprising a FET or

the first electrode having a plurality of separate conductive lines overlaying the diffusion region, or

the first device comprising a diffused electrode that is coupled to said source of programming energy.

Prior art of record fails to teach or suggest to incorporate these limitations into Chen et al. to arrive at the claimed device.

Conclusion

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 571-272-1656. The examiner can normally be reached on Maxiflex.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C Lee can be reached on 703-308-1690. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

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you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

Donghee Kang
Examiner

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